

DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

**HIGH VOLTAGE GENERATION AND REGULATION SYSTEM FOR DIGITAL
MULTILEVEL NONVOLATILE MEMORY**

the specification of which (check one) X is attached hereto or _____ was filed on _____ as Application No. _____ and was amended on _____ (if applicable).

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose all information which is material to patentability as defined in 37 CFR § 1.56.

I hereby claim foreign priority benefits under 35 U.S.C. § 119(a)-(d) or § 365(b) of any foreign application(s) for patent or inventor's certificate, or § 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Prior Foreign Application(s)	<u>Priority Claimed</u>
	<u>Yes</u> <u>No</u>

Number	Country	Day/Month/Year Filed	_____	_____
--------	---------	----------------------	-------	-------

Number	Country	Day/Month/Year Filed	_____	_____
--------	---------	----------------------	-------	-------

I hereby claim the benefit under 35 U.S.C. § 119(e) of any United States provisional application(s) below.

Application Number	Filing Date
--------------------	-------------

Application Number	Filing Date
--------------------	-------------

I hereby claim the benefit under 35 U.S.C. § 120 of any United States application(s), or § 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of 35 U.S.C. § 112, I acknowledge the duty to disclose all information which is material to patentability as defined in 37 CFR § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

Application Number	Filing Date	Status: Patented, Pending, Abandoned
--------------------	-------------	--------------------------------------

Application Number	Filing Date	Status: Patented, Pending, Abandoned
--------------------	-------------	--------------------------------------

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment or both, under 18 U.S.C. § 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of sole or first inventor William John Saiki

Inventor's signature

12/19/01

Date

Residence 706 Mariposa Ave., Apt. #2, Mountain View, California 94041

Citizenship United States of America

Post Office Address 706 Mariposa Ave., Apt. #2, Mountain View, California 94041

Full name of sole or second inventor Hieu Van Tran

Inventor's signature Hieu Van Tran Date 12/19/01

Residence 2741 Coltwood Drive, San Jose, California 95148

Citizenship United States of America

Post Office Address 2741 Coltwood Drive, San Jose, California 95148

Full name of sole or third inventor Sakhawat M. Khan

Inventor's signature Sakhawat M. Khan Date 11/19/01

Residence 574 Panchita Way, Los Altos, California 94022

Citizenship United States of America

Post Office Address 574 Panchita Way, Los Altos, California 94022

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: William J. Saiki et al.

Serial No.: Unknown Group Art Unit: Unknown

Filed: Unknown Examiner: Unknown

Title: **HIGH VOLTAGE GENERATION AND REGULATION SYSTEM FOR DIGITAL MULTILEVEL NONVOLATILE MEMORY**

* * *

POWER OF ATTORNEY BY ASSIGNEE

Assistant Commissioner for Patents
Washington, DC 20231

Sir:

The undersigned, being Assignee of the entire right, title and interest in the above-identified application by virtue of an Assignment, a copy thereof is attached, under 37 C.F.R. §3.71, to prosecute the application to the exclusion of the Inventor(s), and grants Power of Attorney and correspondence address as stated herein.

Silicon Storage Technology, Inc., hereby appoints:

Practitioners at Customer Number: 26379 →



26379
PATENT TRADEMARK OFFICE

as attorneys/agents with full power of substitution and revocation to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith.

Assignee:
Silicon Storage Technology, Inc.

Date: Dec. 18, 2001

Printed Name: Bing Yeh

Title: President